

Data sheet acquired from Harris Semiconductor SCHS076D – Revised March 2004

CMOS Dual Up-Counters

High-Voltage Types (20-Volt Rating)

CD4518B Dual BCD Up-Counter CD4520B Dual Binary Up-Counter

CD4518 Dual BCD Up-Counter and CD4520 Dual Binary Up-Counter each consist of two identical, internally synchronous 4-stage counters. The counter stages are D-type flip-flops having interchangeable CLOCK and ENABLE lines for incrementing on either the positive-going or negative-going transition. For single-unit operation the ENABLE input is maintained high and the counter advances on each positive-going transition of the CLOCK. The counters are cleared by high levels on their RESET lines.

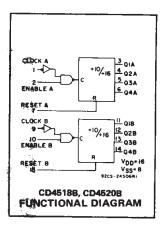
The counter can be cascaded in the ripple mode by connecting Q4 to the enable input of the subsequent counter while the CLOCK input of the latter is held low.

The CD4518B and CD4520B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

MAXIMUM RATINGS, Absolute-Maximum Values:

Features:

- Medium-speed operation —
 6-MHz typical clock frequency at 10 V_☉
- Positive- or negative-edge triggering
- Synchronous internal carry propagation
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin(over full package-temperature range): 1 V at V_{DD} = 5 V
 2 V at V_{DD} = 10 V
 - 2.5 V at $V_{DD} = 15 \text{ V}$
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output
 sharacteristics
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"



Applications:

- Multistage synchronous counting
- Multistage ripple counting
- Frequency dividers

TRUTH TABLE

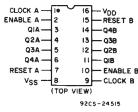
CLOCK	ENABLE	RESET	ACTION
\	1	0	Increment Counter
0	~	0	Increment Counter
7	х	0	No Change
х		0	No Change
	0	0	No Change
1		0	No Change
Х	х	1	Q1 thru Q4 = 0

X = Don't Care	1 = High State	0 ≡ Low Sta

DC SUPPLY-VOLTAGE RANGE, (V_{DD}) Voltages referenced to V_{SS} Terminal) INPUT VOLTAGE RANGE, ALL INPUTS DC INPUT CURRENT, ANY ONE INPUT POWER DISSIPATION PER PACKAGE (PD): For $T_A = -55^{\circ}$ C to $+100^{\circ}$ C For $T_A = +100^{\circ}$ C to $+125^{\circ}$ C. Derate Linearity at $12mW/^{\circ}$ C to 200mW

For T _A = -55°C to +100°C	500mW
For T _A = +100°C to +125°C	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package	Types)
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)	65°C to +150°C

LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ inch $(1.59 \pm 0.79$ mm) from case for 10s	max +265°C



CD4518B, CD4520B TERMINAL ASSIGNMENT

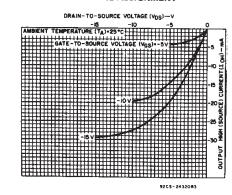


Fig. 3 — Typical output high (source) current characteristics.

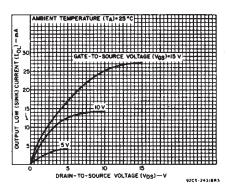


Fig. 1 — Typical output low (sink) current characteristics.

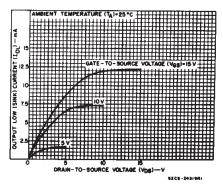


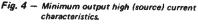
Fig. 2 – Minimum output low (sink) current characteristics.

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	COND	HOITION	IS	LIMITS AT INDICATED TEMPERATURES (°C)							
ISTIC	Vo	VIN	VDD		_	17.7			+25		UNITS
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device Current, IDD Max.		0,5	5	5	5	150	150	_ "	0.04	5	μÀ
		0,10	10	10	10	300	300		0.04	10	
		0,15	15	20	20	600	600	_	0.04	20	
	-	0,20	20	100	100	3000	3000	-	0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	.0.9	1.3	2.6	-	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	-	
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
Current, IOH Min.	9,5	0,10	10	-1.6	-1.5	-1.1	0.9	-1.3	-2.6	-	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage:	_	0,5	5	0.05				_	0	0.05	
Low-Level, VOL Max.	-	0,10	10		0.05				0	0.05	
* ULax.	_	0,15	15		0	.05			. 0	0.05	v
Output Voltage:	<u>`</u> +	0,5	5	4.95				4.95	5	_	ľ
High-Level,		0,10	<i>⊸</i> 10		9	.95		9.95	10	_	
VOH Min.	-	0,15	15		14	1.95		14.95	15	-	
Input Low	0.5, 4.5	-	5		1	.5		_		1.5	
Voltage, Vij Max.	1, 9	_	10			3		_		3	
AIL MIGN.	1.5,13.5	_	15			4		1	_	4	v
Input High	0.5, 4.5		5		3	3.5		3.5	_		· •
Voltage,	1, 9	_	10			7		7			1
VIH Min.	1.5,13.5	-	15			11		11		_	
Input Current IIN Max.	_	0,18	18	±0.1	±0.1	±1	±1	- (±10 ⁻⁵	±0.1	μА



DRAIN-TO-SOURCE VOLTAGE (VDS)



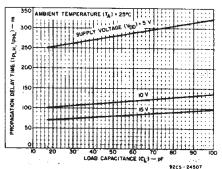


Fig. 5 - Typical propagation delay vs. load capacitance, clock or enable to output.

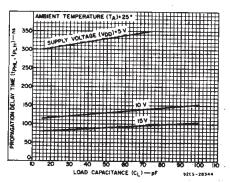


Fig. 6 — Typical propagation delay time vs. load capacitance, reset to output.

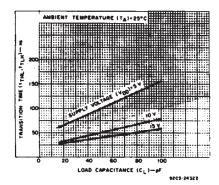
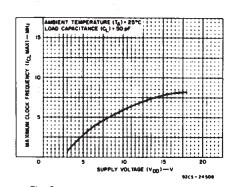


Fig. 7 - Typical transition time vs. load capacitance.



CD4518B, CD4520B Types

Fig. 8 — Typical maximum-clock-frequency vs. supply voltage.

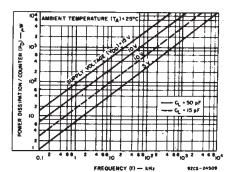


Fig. 9 - Typical power dissipation characteristics.

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}C$, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V _{DD}	LII	MITS	UNITS
	(V)	Min.	Max.	1
Supply Voltage Range (For TA=Full Package- Temperature Range)		3	18	V
	5	400	· -	
Enable Pulse Width, t _W	10	200	- .	ns
	15	140		
	5	200	- `	
Clock Pulse Width, tw	10	100		ns
	15	. 70	. =	
	5		1.5	
Clock Input Frequency, fCL	10	dc	3	MHz
	15		. 4	, , , , , , , , , , , , , , , , , , ,
Clock Rise or Fall Time, t _r CL or t _f CL:	5 10 15		15 5 5	μs
	5	250	-	
Reset Pulse Width, tw	10	. 110		ns
**	15	80		

DYNAMIC ELECTRICAL CHARACTERISTICS at TA=25°C; Input tr,tq=20 ns, CL=50 pF, RL=200 K Ω

CHARACTERISTIC	TEST CON	DITIONS	L	IMIT	S	UNITS
		V _{DD}	Min.	Typ.	Max.	
Propagation Delay Time, tpHL, tpLH: Clock or Enable to Output		5 10 15	- -	280 115 80	560 230 160	
Reset to Output		5 10 15	-	330 130 90	650 225 170	ns
Transition Time, t _{THL} , t _{TLH}		5 10 15		100 50 40	200 100 80	ns
Maximum Clock Input Frequency, fCL		5 10 15	1.5 3 4	3 6 8	-	MHz
Minimum Clock Pulse Width, t _W		5 10 15		100 50 35	200 100 70	ns
Clock Rise or Fall Time, t _r or t _f :		5 10, 15	1	.1 4	15 5	μς
Minimum Reset Pulse Width, tw		5 10 15	-	125 55 40	250 110 80	ns
Minimum Enable Pulse Width, tw		5 10 15	-	200 100 70	400 200 140	ns
Input Capacitance, C _{IN}	Any Input			5	7.5	ρF

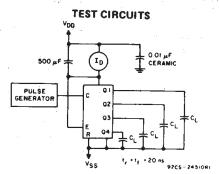


Fig. 10 — Dynamic power dissipation.

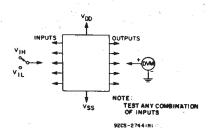


Fig. 11 - Input voltage.

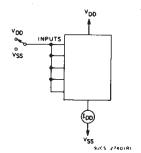


Fig. 12 — Quiescent device current test circuit.

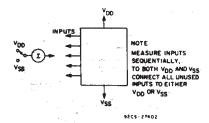
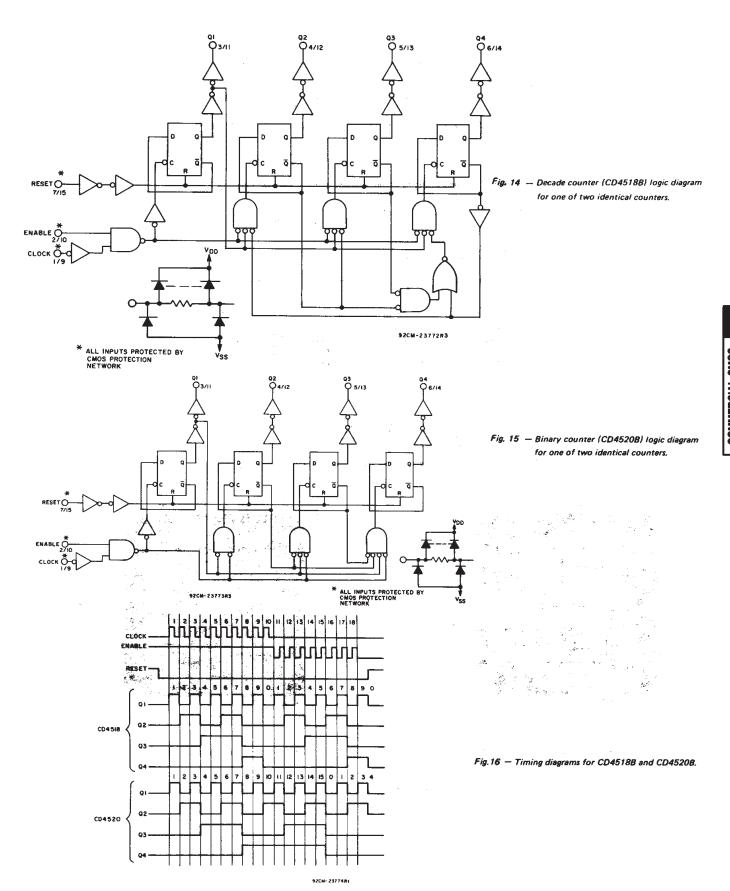


Fig. 13 — Input leakage-current test oircuit.



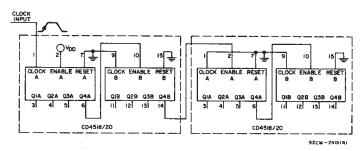
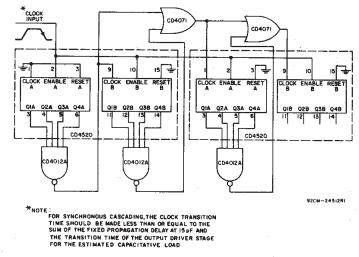
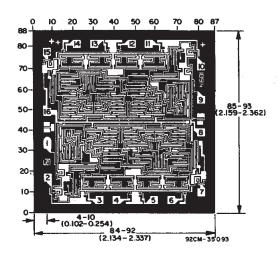


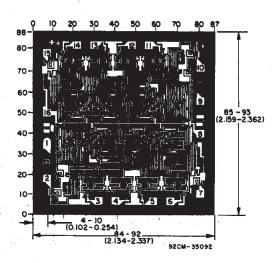
Fig. 17 - Ripple cascading of four counters with positive edge triggering.



 ${\it Fig. 18-Synchronous\ cascading\ of\ four\ binary\ counters\ with\ negative\ edge\ triggering.}$



Dimensions and pad layout for CD45188H chip.



Dimensions and pad layout for CD4520BH chip.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils $(10^{-3} \, \text{inch})$.





22-Jul-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
7702301EA	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	7702301EA CD4520BF3A	Samples
CD4518BE	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD4518BE	Samples
CD4518BEE4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD4518BE	Samples
CD4518BF	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD4518BF	Samples
CD4518BF3A	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD4518BF3A	Samples
CD4518BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4518BM	Samples
CD4518BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4518BM	Samples
CD4518BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4518B	Samples
CD4518BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM518B	Samples
CD4518BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM518B	Samples
CD4518BPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM518B	Samples
CD4518BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM518B	Samples
CD4520BE	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD4520BE	Samples
CD4520BEE4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD4520BE	Samples
CD4520BF	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD4520BF	Samples
CD4520BF3A	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	7702301EA CD4520BF3A	Samples
CD4520BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4520BM	Samples



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PACKAGE OPTION ADDENDUM

22-.lul-2020

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4520BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4520BM	Samples
CD4520BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4520BM	Samples
CD4520BMG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4520BM	Samples
CD4520BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4520B	Samples
CD4520BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM520B	Samples
CD4520BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM520B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

22-Jul-2020

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4518B, CD4518B-MIL, CD4520B, CD4520B-MIL:

Military: CD4518B-MIL, CD4520B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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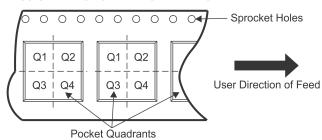
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4518BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4518BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4518BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4520BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4520BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4520BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4518BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4518BNSR	SO	NS	16	2000	367.0	367.0	38.0
CD4518BPWR	TSSOP	PW	16	2000	853.0	449.0	35.0
CD4520BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4520BNSR	SO	NS	16	2000	367.0	367.0	38.0
CD4520BPWR	TSSOP	PW	16	2000	853.0	449.0	35.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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